ESD9B, SZESD9B

Transient Voltage Suppressors

Micro-Packaged Diodes for ESD Protection

The ESD9B Series is designed to protect voltage sensitive components from ESD. Excellent clamping capability, low leakage, and fast response time provide best in class protection on designs that are exposed to ESD. Because of its small size, it is suited for use in cellular phones, MP3 players, digital cameras and many other portable applications where board space comes at a premium.

Specification Features

- Low Capacitance 15 pF
- Low Clamping Voltage
- Small Body Outline Dimensions: 0.039" x 0.024" (1.0mm x 0.60mm)
- Low Body Height: 0.016" (0.4 mm)
- Stand-off Voltage: 3.3 V, 5 V
- Low Leakage
- Response Time is < 1 ns
- IEC61000-4-2 Level 4 ESD Protection
- AEC-Q101 Qualified and PPAP Capable
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements
- This is a Pb-Free Device

Mechanical Characteristics

CASE: Void-free, transfer-molded, thermosetting plastic

Epoxy Meets UL 94 V-0

LEAD FINISH: 100% Matte Sn (Tin)

MOUNTING POSITION: Any

QUALIFIED MAX REFLOW TEMPERATURE: 260°C

Device Meets MSL 1 Requirements

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
IEC 61000-4-2 (ESD) Contact Air		±18 ±18	kV
IEC 61000-4-4 (EFT)		40	Α
Total Power Dissipation on FR-5 Board (Note 1) @ T _A = 25°C	P_{D}	300	mW
Thermal Resistance, Junction-to-Ambient	$R_{\theta JA}$	400	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature – Maximum (10 Second Duration)	T_L	260	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1

1. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.



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SOD-923 CASE 514AB

MARKING DIAGRAM



= Specific Device Code

M Date Code

ORDERING INFORMATION

Device	Package	Shipping [†]
ESD9B3.3ST5G	SOD-923 (Pb-Free)	8000/Tape & Reel
ESD9B5.0ST5G	SOD-923 (Pb-Free)	8000/Tape & Reel
SZESD9B5.0ST5G	SOD-923 (Pb-Free)	8000/Tape & Reel

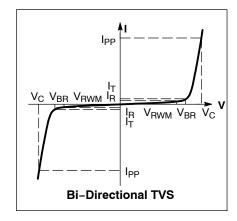
†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ESD9B, SZESD9B

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

\ A	,
Symbol	Parameter
I _{PP}	Maximum Reverse Peak Pulse Current
V _C	Clamping Voltage @ I _{PP}
V _{RWM}	Working Peak Reverse Voltage
I _R	Maximum Reverse Leakage Current @ V _{RWM}
V_{BR}	Breakdown Voltage @ I _T
I _T	Test Current
С	Capacitance @ V _R = 0 V and f = 1.0 MHz

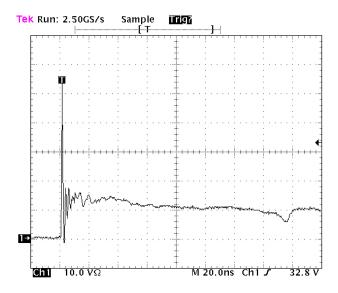


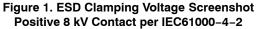
ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

		V _{RWM} (V)	I _R (μΑ) @ V _{RWM}	V _{BR} (V) @ I _T (Note 2)				I _T	C (pF)	V _C	V _C (V) @ I _{PP} = 1 A
Device	Device Marking	Max	Max	Min	Max	mA	Тур	Per IEC61000-4-2 (Note 3)	Max Per 8 x 20 μs (Note 4)		
ESD9B3.3ST5G	2*	3.3	1.0	5.0	7.0	1.0	15	Figures 1 and 2 See Below	10.5		
ESD9B5.0ST5G, SZESD9B5.0ST5G	E	5.0	1.0	5.8	7.8	1.0	15	Figures 1 and 2 See Below	12.5		

^{*} Rotated 270°.

- 2. V_{BR} is measured with a pulse test current I_{T} at an ambient temperature of 25°C.
- 3. For test procedure see Figures 3 and 4 and Application Note AND8307/D.
- 4. Surge current waveforms per Figure 5.





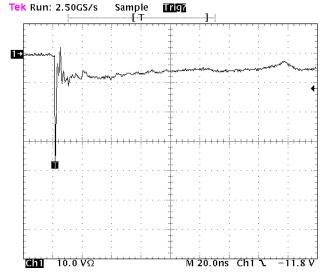


Figure 2. ESD Clamping Voltage Screenshot Negative 8 kV Contact per IEC61000-4-2

IEC 61000-4-2 Spec.

	-			
Level	Test Voltage (kV)	First Peak Current (A)	Current at 30 ns (A)	Current at 60 ns (A)
1	2	7.5	4	2
2	4	15	8	4
3	6	22.5	12	6
4	8	30	16	8

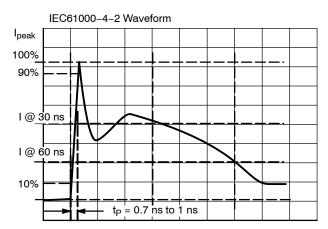


Figure 3. IEC61000-4-2 Spec

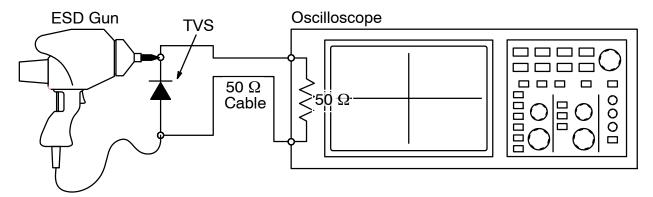


Figure 4. Diagram of ESD Test Setup

The following is taken from Application Note AND8308/D – Interpretation of Datasheet Parameters for ESD Devices.

ESD Voltage Clamping

For sensitive circuit elements it is important to limit the voltage that an IC will be exposed to during an ESD event to as low a voltage as possible. The ESD clamping voltage is the voltage drop across the ESD protection diode during an ESD event per the IEC61000-4-2 waveform. Since the IEC61000-4-2 was written as a pass/fail spec for larger

systems such as cell phones or laptop computers it is not clearly defined in the spec how to specify a clamping voltage at the device level. ON Semiconductor has developed a way to examine the entire voltage waveform across the ESD protection diode over the time domain of an ESD pulse in the form of an oscilloscope screenshot, which can be found on the datasheets for all ESD protection diodes. For more information on how ON Semiconductor creates these screenshots and how to interpret them please refer to AND8307/D.

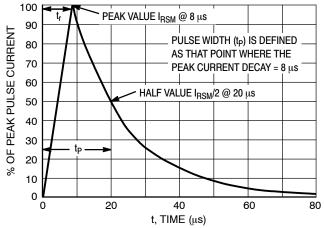
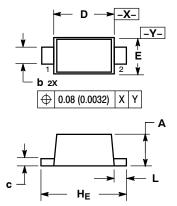


Figure 5. 8 X 20 µs Pulse Waveform

ESD9B, SZESD9B

PACKAGE DIMENSIONS

SOD-923 CASE 514AB-01 **ISSUE B**

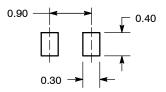


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI
- 714.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETERS.
 MAXIMUM LEAD THICKNESS INCLUDES LEAD
 FINISH THICKNESS. MINIMUM LEAD
- THICKNESS IS THE MINIMUM THICKNESS OF BASE MATERIAL.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.34	0.37	0.40	0.013	0.015	0.016
b	0.15	0.20	0.25	0.006	0.008	0.010
С	0.07	0.12	0.17	0.003	0.005	0.007
D	0.75	0.80	0.85	0.030	0.031	0.033
Е	0.55	0.60	0.65	0.022	0.024	0.026
HE	0.95	1.00	1.05	0.037	0.039	0.041
L	0.05	0.10	0.15	0.002	0.004	0.006

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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